1. (Currently Amended) A semiconductive polyvinylidene fluoride resin composition comprising 100 parts by weight of a polyvinylidene fluoride resin (A), 0.03 to 10 parts by weight of at least one quaternary ammonium ~~tetraalkylammonium~~ salt (B) selected from the group consisting of tetraalkylammonium sulfates (B1) represented by the formula (1):

(1)

wherein R^1 to R^4 are alkyl groups which are the same or different from one another, and R^5 is an alkyl or fluoroalkyl group or a hydrogen atom, and tetraalkylammonium sulfites (B2) represented by the formula (2):

(2)

wherein R^6 to R^9 are alkyl groups which are the same or different from one another, and R^{10} is an alkyl or fluoroalkyl group or a hydrogen atom, and 2 to 15 ~~1 to 20~~ parts by weight of at least one conductive carbon black (C) selected from the group consisting of acetylene black and conductive oil furnace black and having a DBP oil absorption of at least 100 ml/100 g, and wherein the semiconductive polyvinylidene fluoride resin composition has a volume resistivity within a range of 10^4 to 10^{12} Ωcm.

2. (Original) The semiconductive polyvinylidene fluoride resin composition according to Claim 1, wherein the polyvinylidene fluoride resin (A) is at least one polyvinylidene fluoride resin selected from the group consisting of a homopolymer of vinylidene fluoride, vinylidene fluoride-hexafluoropropylene copolymers, vinylidene fluoride-tetrafluoroethylene copolymers and vinylidene fluoride-tetrafluoroethylene-hexafluoropropylene terpolymers.

3. (Original) The semiconductive polyvinylidene fluoride resin composition according to Claim 1, wherein the quaternary ammonium salt (B) is a tetraalkylammonium hydrogensulfate in which R^5 in the formula (1) is a hydrogen atom.

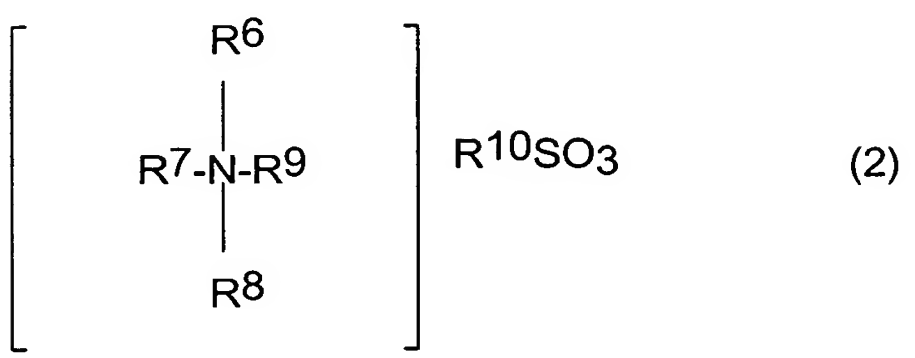
4. (Original) The semiconductive polyvinylidene fluoride resin composition according to Claim 3, wherein the tetraalkylammonium hydrogensulfate is tetrabutylammonium hydrogensulfate $[(C_4H_9)_4N(HSO_4)]$.

5-6. (Cancelled).

7. (Currently Amended) A formed or molded product composed of a semiconductive polyvinylidene fluoride resin composition comprising 100 parts by weight of a polyvinylidene fluoride resin (A), 0.03 to 10 parts by weight of at least one quaternary ammonium ~~tetraalkylammonium~~ salt (B) selected from the group consisting of tetraalkylammonium sulfates (B1) represented by the formula (1):

$$\left[\begin{array}{c} R^1 \\ | \\ R^2\text{-}N\text{-}R^4 \\ | \\ R^3 \end{array}\right] R^5SO_4 \qquad (1)$$

wherein R^1 to R^4 are alkyl groups which are the same or different from one another, and R^5 is an alkyl or fluoroalkyl group or a hydrogen atom, and tetraalkylammonium sulfites (B2) represented by the formula (2):



$$\left[\begin{array}{c} R^6 \\ | \\ R^7\text{-}N\text{-}R^9 \\ | \\ R^8 \end{array}\right] R^{10}SO_3 \qquad (2)$$

wherein R^6 to R^9 are alkyl groups which are the same or different from one another, and R^{10} is an alkyl or fluoroalkyl group or a hydrogen atom, and 2 to 15 ~~1 to 20~~ parts by weight of at least one conductive carbon black (C) selected from the group consisting of acetylene black and conductive oil furnace black and having a DBP oil absorption of at least 100 ml/100 g, and wherein the semiconductive polyvinylidene fluoride resin composition has a volume resistivity within a range of 10^4 to 10^{12} Ωcm.

8. (Original) The formed or molded product according to Claim 7, wherein the polyvinylidene fluoride resin (A) is at least one polyvinylidene fluoride resin selected from the group consisting of a homopolymer of vinylidene fluoride, vinylidene fluoride-

hexafluoropropylene copolymers, vinylidene fluoride-tetrafluoroethylene copolymers and vinylidene fluoride-tetrafluoroethylene-hexafluoropropylene terpolymers.

9. (Original) The formed or molded product according to Claim 7, wherein the quaternary ammonium salt (B) is a tetraalkylammonium hydrogensulfate in which R^5 in the formula (1) is a hydrogen atom.

10. (Original) The formed or molded product according to Claim 9, wherein the tetraalkylammonium hydrogensulfate is tetrabutylammonium hydrogensulfate $[(C_4H_9)_4N(HSO_4)]$.

11-12. (Cancelled).

13. (Original) The formed or molded product according to Claim 7, which is a sheet, tube, seamless belt, fiber, container, roll or injection-molded product.

14. (Original) The formed or molded product according to Claim 7, which is a static charge controlling member at least the surface layer of which has been formed from the semiconductive polyvinylidene fluoride resin composition.

15. (Original) The formed or molded product according to Claim 14, wherein the static charge controlling member is a charging member or static charge eliminating member used in an image forming apparatus of an electrophotographic system.

16. (Original) The formed or molded product according to Claim 14, wherein the static charge controlling member is a packaging material for electronic parts, wall paper, sheathing material for OA apparatus, anti-static partition, conveyor tube for fuels or conveyor tube for powder coatings.